

## Supporting Information

### Electric-field-tunable molecular adsorption on germanane

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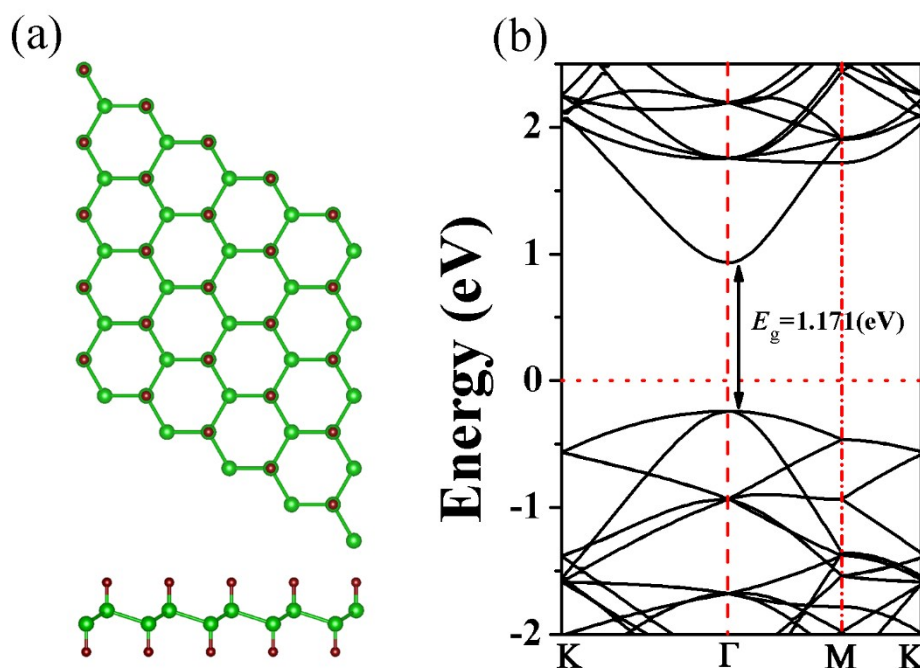


Fig. S1 (a) The top and side views of germanane. The green and brown spheres represent Ge and H atom, respectively. (b) The band structures of germanane. The Fermi level is set to 0 eV.

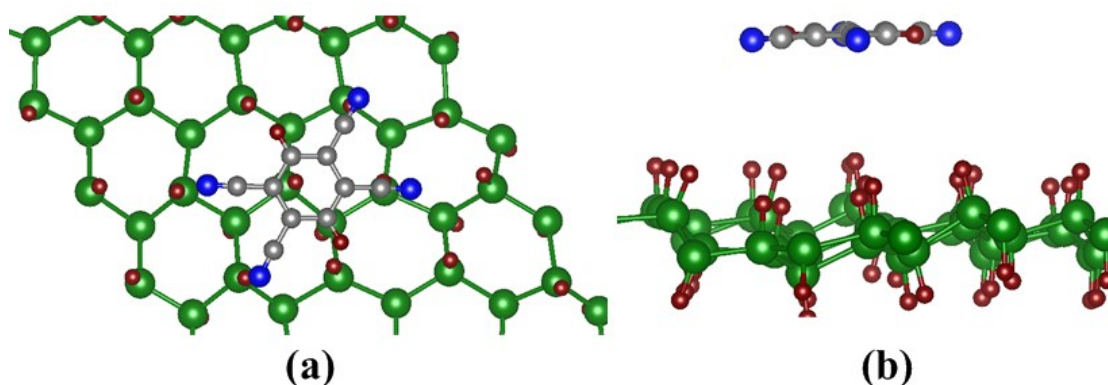


Fig. S2 (a)-(b) The top view and side view of germanane/TCNB under 300k for 10 ps.

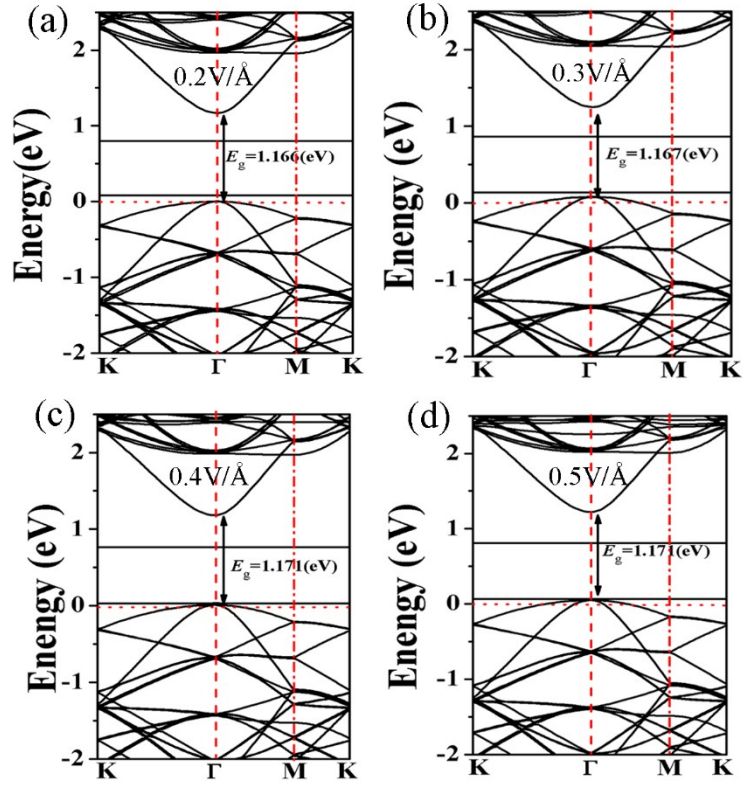


Fig. S3 (a)-(d) The band structures of germanane/TCNB under E-field of 0.2 V/Å, 0.3 V/Å, 0.4 V/Å and 0.5 V/Å, respectively. The Fermi level is set to 0 eV.

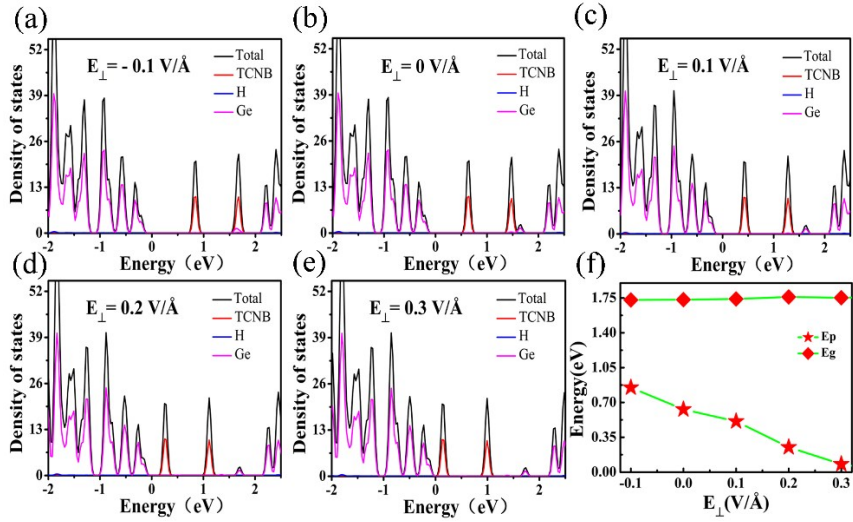


Fig. S4 The projected density of states for germanane/TCNB and the evolution of  $E_p$  under different E-field by using HSE06 method

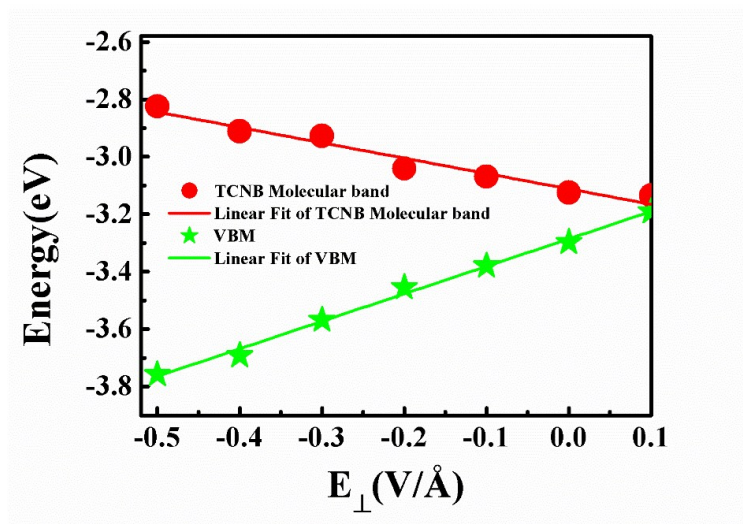


Fig. S5 The energies for VBM at  $\Gamma$ -point and the empty band minimum of TCNB with respect to Fermi level in conduction bands as a function vs E-field ranged from  $-0.5\text{V}/\text{\AA}$  to  $0.1\text{ V}/\text{\AA}$ .